

BD439 - BD441

SILICON NPN POWER TRANSISTORS.

The BD439-BD441 are NPN Transistors mounted in Jedec TO-126 plastic package. They are recommended for use in medium power linear and switching applications. PNP complements are BD440-BD442. Compliance to RoHS.

ABSOLUTE MAXIMUM RATINGS

| Symbol | Ratings | | Value | Unit | |
|------------------|---|----------------------|-------------|---------------|--|
| V _{CBO} | (Collector-Base Voltage (I ()) | 3D439 | 60 | V | |
| | | 3D441 | 80 | \ \ \ \ | |
| V _{CEO} | (Collector-Emitter Voltage (Is= ()) | 3D439 | 60 | V | |
| | | 3D441 | 80 | V | |
| V_{EBO} | Emitter-Base Voltage (I _c = 0) | | 5 | V | |
| Ic | Collector Current | | 4 | ۸ | |
| I _{CM} | Collector Current Peak | | 7 | А | |
| I _B | Base Current | | 1 | Α | |
| Pc | Total power Dissipation | Γ _C = 25℃ | 36 | W | |
| T_{J} | Junction Temperature | | 150 | ${\mathbb C}$ | |
| T _{Stq} | Storage Temperature | · | -65 to +150 | $\mathcal C$ | |

THERMAL CHARACTERISTICS

| Symbol | Ratings | Value | Unit |
|--------------------|--|-------|------|
| R _{thJ-c} | Thermal Resistance, Junction-Case | 3.5 | €\M |
| R_{thJ-a} | Thermal Resistance, Junction-ambient in free air | 100 | €\M |



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ELECTRICAL CHARACTERISTICS

TC=25℃ unless otherwise noted

| Symbol | Ratings | Test Condition | on(s) | Min | Тур | Max | Unit |
|-----------------------|--|--|----------------|----------|------|------------|------|
| І _{сво} | Collector cut-off current | $I_E = 0$, $V_{CB} = 60 \text{ V}$ $I_E = 0$, $V_{CB} = 80 \text{ V}$ | BD439 BD441 | - | - | 100 | _ |
| I _{CES} | Collector cut-off current | $V_{BE} = 0, V_{CE} = 60 \text{ V}$ $V_{BE} = 0, V_{CE} = 80 \text{ V}$ | BD439 BD441 | - | - | 100 | μA |
| I _{EBO} | Emitter cut-offcurrent | I _C = 0 V _{EB} = 5 V | BD439 BD441 | _ | - | 1 | mA |
| V _{CEO(SUS)} | Collector-Emitter sustaning Voltage (*) | I _B = 0 I _C = 100 mA | BD439 BD441 | 60 80 | - | - | V |
| V _{CE(SAT)} | Collector-Emitter saturation Voltage (*) | I _C = 2 A I _B = 200 mA | BD439 BD441 | - | - | 0.8 | V |
| | Base-Emitter Voltage(*) | I _C = 10 mA V _{CE} = 5 V | BD439 BD441 | - | 0.58 | - | V |
| V _{BE} | | I _C = 2 A V _{CE} = 1 V | BD439 BD441 | - | - | 1.5 | V |
| h _{FE} | DC Current Gain (*) | I _C = 10 mA V _{CE} = 5 V | BD439 BD441 | 20 15 | - | 130 130 | |
| | | I _C = 500 mA V _{CE} = 1 V | BD439 BD441 | 40 | - | 140 | - |
| | | I _C = 2 A V _{CE} = 1 V | BD439 BD441 | 25 15 | - | - | |
| f _T | Transition frequency | I _C = 250 mA V _{CE} = 1 V | BD439 BD441 | - 3 | - | - | MHz |

^(*) Measured under pulse conditions : t_P <300 μ s, δ <1.5%

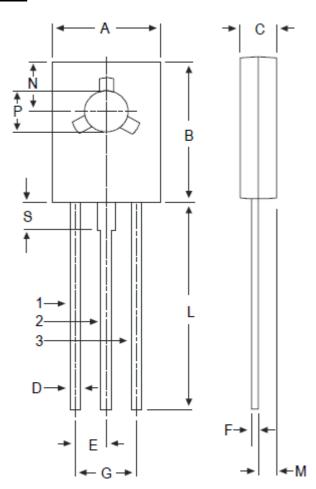


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MECHANICAL DATA CASE TO-126

| | DIMENSIONS | | |
|---|------------|-----------|--|
| | min | max | |
| Α | 7.4 | 7.8 | |
| В | 10.5 | 10.8 | |
| С | 2.4 | 2.7 | |
| D | 0.7 | 0.9 | |
| Е | 2.25 typ. | | |
| F | 0.49 | 0.75 | |
| G | 4.4 typ. | | |
| ١ | 15.7 typ. | | |
| М | 1.27 | 1.27 typ. | |
| Ν | 3.75 typ. | | |
| Р | 3.0 | 3.2 | |
| S | 2.54 typ. | | |

| Pin 1 : | Emitter |
|---------|-----------|
| Pin 2 : | Collector |
| Pin 3 : | Base |



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